

SD103N/R SERIES

FAST RECOVERY DIODES

Stud Version

Features

- High power FAST recovery diode series
- 1.0 to 2.0 μ s recovery time
- High voltage ratings up to 2500V
- High current capability
- Optimized turn on and turn off characteristics
- Low forward recovery
- Fast and soft reverse recovery
- Compression bonded encapsulation
- Stud version JEDEC DO-30
- Maximum junction temperature 125°C

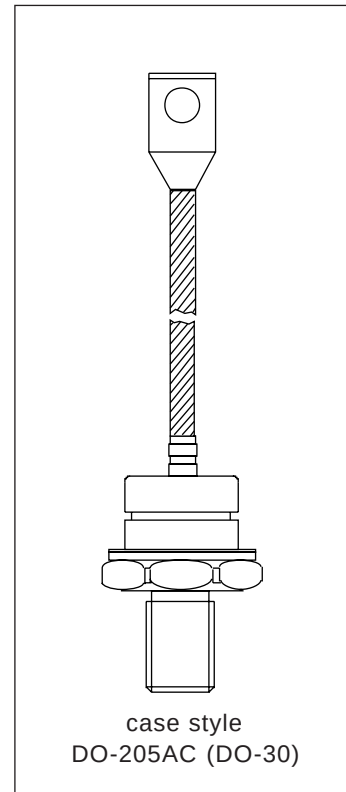
110A

Typical Applications

- Snubber diode for GTO
- High voltage free-wheeling diode
- Fast recovery rectifier applications

Major Ratings and Characteristics

Parameters	SD103N/R	Units
$I_{F(AV)}$	110	A
@ T_C	85	°C
$I_{F(RMS)}$	173	A
I_{FSM} @ 50Hz	3570	A
@ 60Hz	3730	A
I^2t @ 50Hz	64	KA ² s
@ 60Hz	58	KA ² s
V_{RRM} range	400 to 2500	V
t_{rr} range	1.0 to 2.0	μ s
@ T_J	25	°C
T_J	- 40 to 125	°C



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Bulletin I2062 rev. B 12/96

International
IR Rectifier

ELECTRICAL SPECIFICATIONS

Voltage Ratings

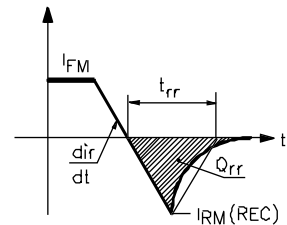
Type number	Voltage Code	V_{RRM} max. repetitive peak and off-state voltage V	V_{RSM} maximum non-repetitive peak voltage V	I_{RRM} max. $T_J = 125^\circ\text{C}$ mA
SD103N/R..S10	04	400	500	35
	08	800	900	
	10	1000	1100	
SD103N/R..S15	12	1200	1300	
	14	1400	1500	
	16	1600	1700	
SD103N/R..S20	20	2000	2100	
	25	2500	2600	

Forward Conduction

Parameter	SD103N/R	Units	Conditions
$I_{F(AV)}$ Max. average forward current @ Case temperature	110 85	A °C	180° conduction, half sine wave.
$I_{F(RMS)}$ Max. RMS current	173	A	DC @ 75°C case temperature
I_{FSM} Max. peak, one-cycle non-repetitive forward current	3570 3730 3000 3140	A	t = 10ms t = 8.3ms t = 10ms t = 8.3ms No voltage reappplied 100% V_{RRM} reappplied
I^2t Maximum I^2t for fusing	64 58 45 41		t = 10ms t = 8.3ms t = 10ms t = 8.3ms No voltage reappplied 100% V_{RRM} reappplied
$I^2\sqrt{t}$ Maximum $I^2\sqrt{t}$ for fusing	636	KA^2s	t = 0.1 to 10ms, no voltage reappplied
$V_{F(TO)1}$ Low level of threshold voltage	1.36	V	$(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)}), T_J = T_J \text{ max.}$
$V_{F(TO)2}$ High level of threshold voltage	1.94		$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ max.}$
r_{f1} Low level of forward slope resistance	2.55	$\text{m}\Omega$	$(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)}), T_J = T_J \text{ max.}$
r_{f2} High level of forward slope resistance	1.11		$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ max.}$
V_{FM} Max. forward voltage	2.23	V	$I_{pk} = 345\text{A}, T_J = 25^\circ\text{C}, t_p = 400 \mu\text{s}$ square pulse

Recovery Characteristics

Code	$T_J = 25^\circ\text{C}$ typical t_{rr} @ 25% I_{RRM} (μs)	Test conditions			Max. values @ $T_J = 125^\circ\text{C}$		
		I_{pk} Square Pulse (A)	di/dt (A/ μs)	V_r (V)	t_{rr} @ 25% I_{RRM} (μs)	Q_{rr} (μC)	I_{rr} (A)
S10	1.0	350	25	-30	1.6	21	27
S15	1.5				2.3	61	37
S20	2.0				3.2	75	39



Thermal and Mechanical Specification

Parameter	SD103N/R	Units	Conditions
T_J Max. operating temperature range	-40 to 125	°C	
T_{stg} Max. storage temperature range	-40 to 150		
R_{thJC} Max. thermal resistance, junction to case	0.16	K/W	DC operation
R_{thCS} Max. thermal resistance, case to heatsink	0.10		Mounting surface, smooth, flat and greased
T Mounting torque $\pm 10\%$	15.5	Nm	Not lubricated threads
	13.5		Lubricated threads
wt Approximate weight	120	g	
Case style	DO-205AC(DO-30)		See Outline Table

ΔR_{thJC} Conduction

(The following table shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC)

Conduction angle	Sinusoidal conduction	Rectangular conduction	Units	Conditions
180°	0.011	0.012	K/W	$T_J = T_{J \text{ max.}}$
120°	0.016	0.019		
90°	0.021	0.023		
60°	0.029	0.030		
30°	0.041	0.041		

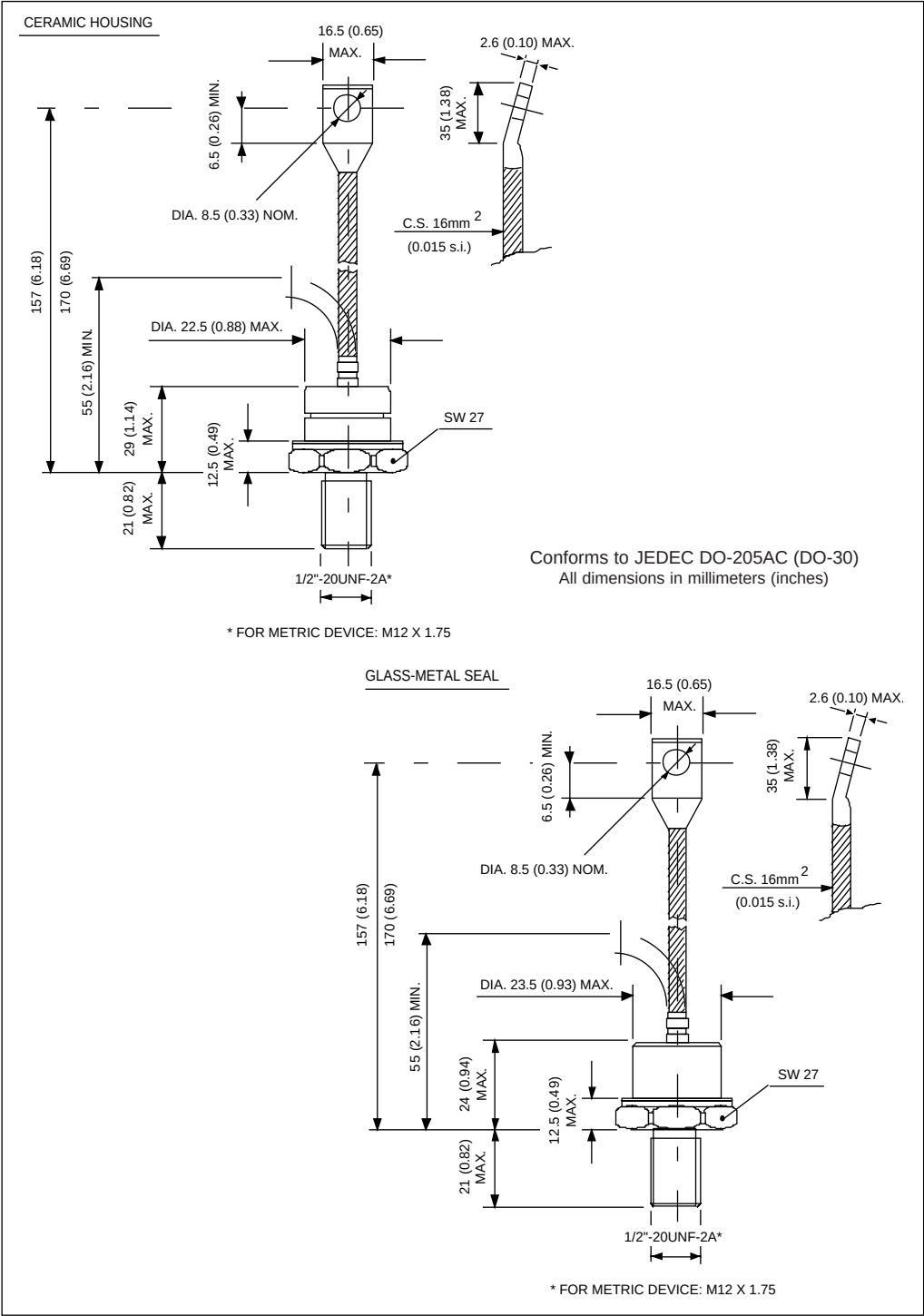
Ordering Information Table

Device Code								
SD	10	3	R	25	S20	P	B	C
①	②	③	④	⑤	⑥	⑦	⑧	⑨
1	- Diode							
2	- Essential part number							
3	- 3 = Fast recovery							
4	- N = Stud Normal Polarity (Cathode to Stud) R = Stud Reverse Polarity (Anode to Stud)							
5	- Voltage code: Code x 100 = V_{RRM} (see Voltage Ratings table)							
6	- t_{rr} code (see Recovery Characteristics table)							
7	- P = Stud base DO-205AC (DO-30) 1/2" 20UNF-2A M = Stud base DO-205AC (DO-30) M12 X 1.75							
8	- B = Flag top terminals (for Cathode/ Anode Leads) S = Isolated lead with silicone sleeve (Red = Reverse Polarity; Blue = Normal Polarity) None = Not isolated lead							
9	- C = Ceramic housing (over 1600V) V = Glass-metal seal (only up to 1600V)							

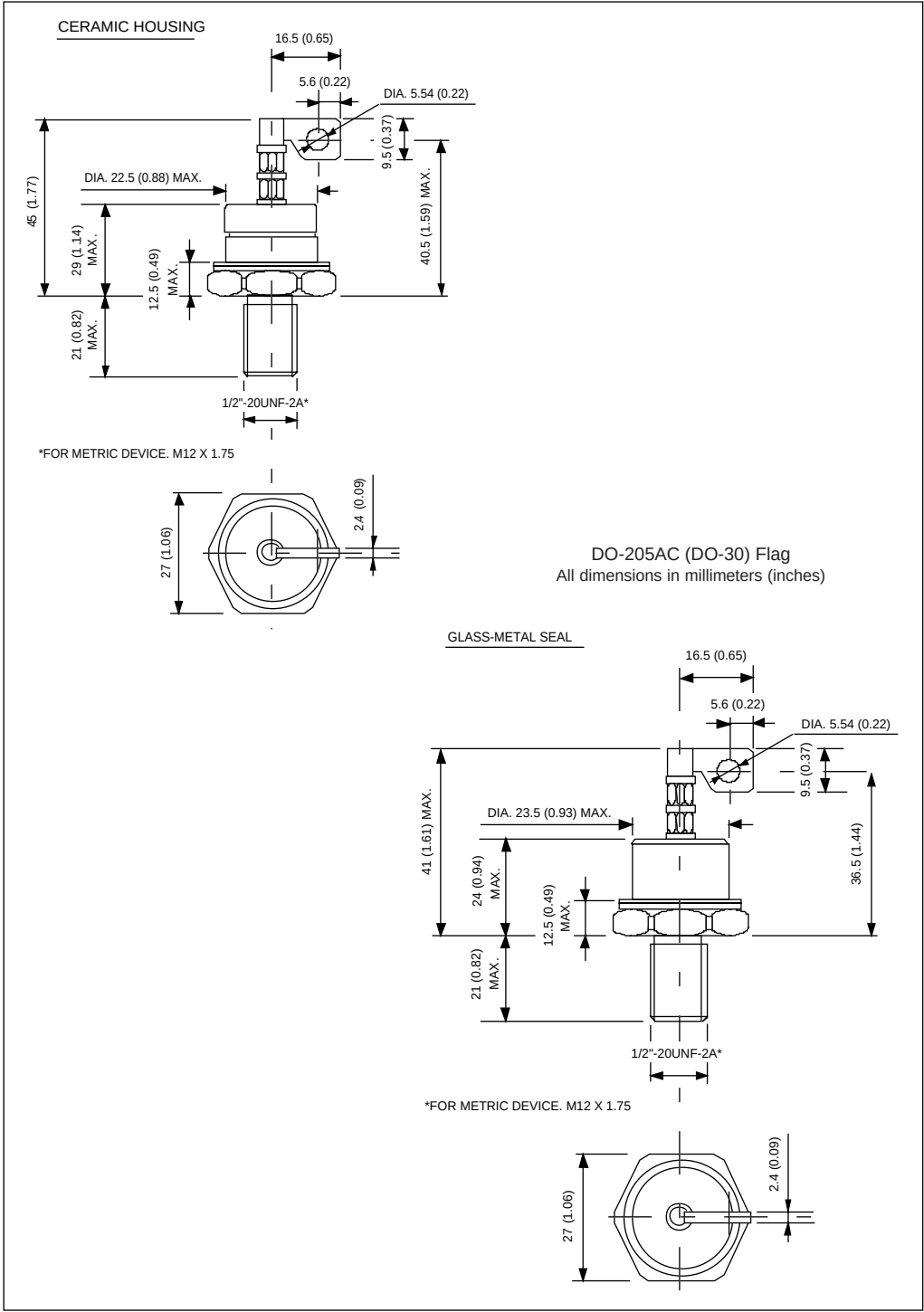
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Outline Table



Outline Table



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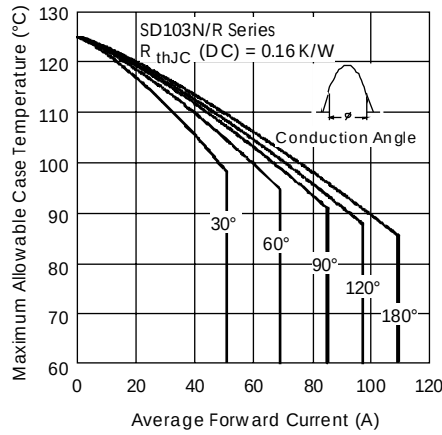


Fig. 1 - Current Ratings Characteristics

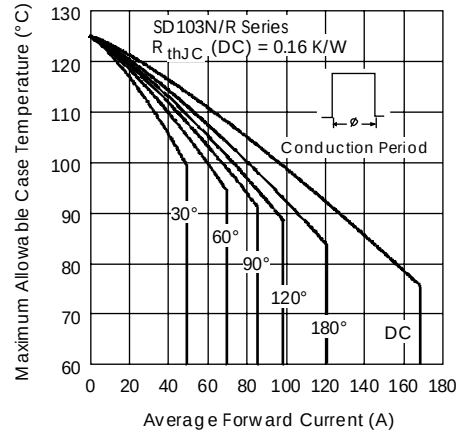


Fig. 2 - Current Ratings Characteristics

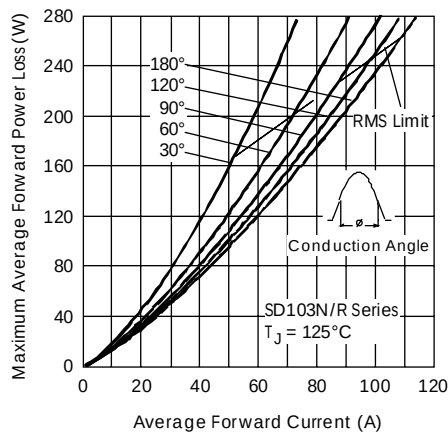


Fig. 3 - Forward Power Loss Characteristics

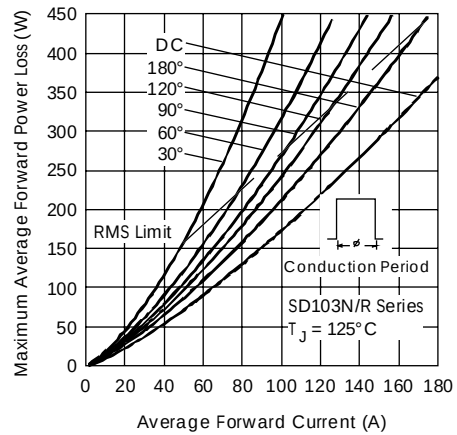


Fig. 4 - Forward Power Loss Characteristics

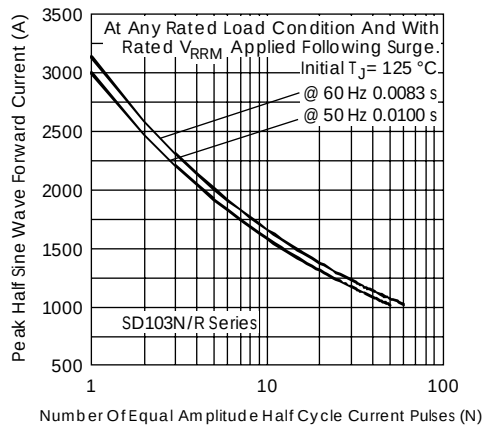


Fig. 5 - Maximum Non-repetitive Surge Current

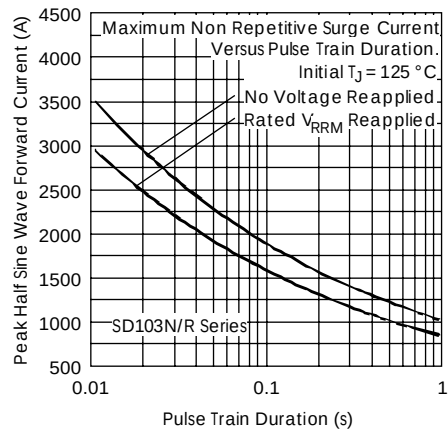


Fig. 6 - Maximum Non-repetitive Surge Current

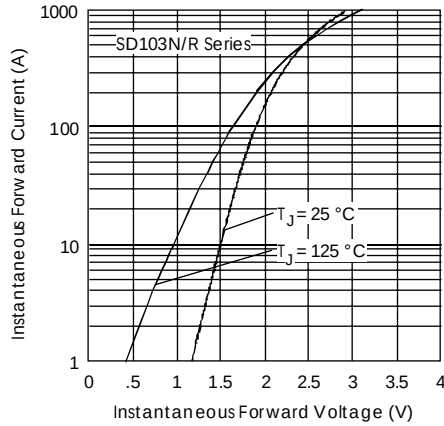


Fig. 7 - Forward Voltage Drop Characteristics

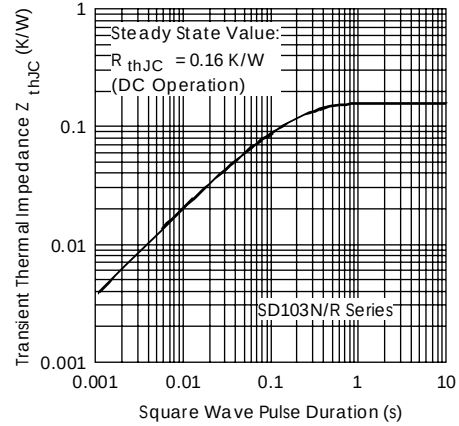


Fig. 8 - Thermal Impedance Z_{thJC} Characteristic

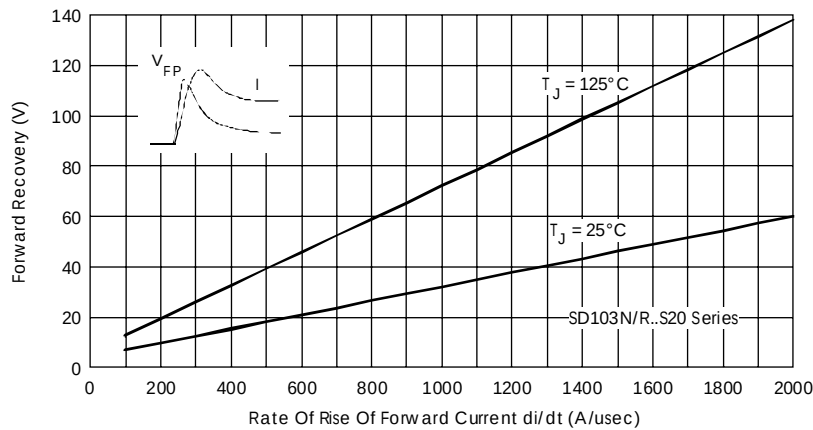
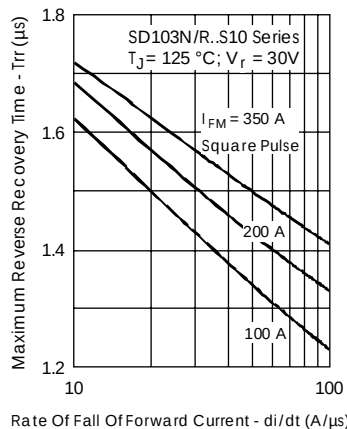
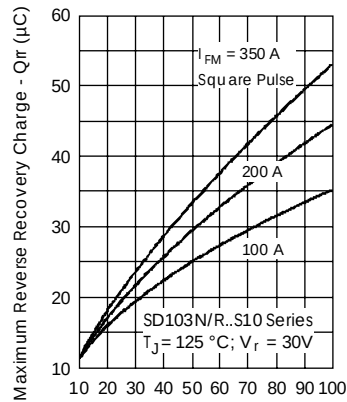


Fig. 9 - Typical Forward Recovery Characteristics



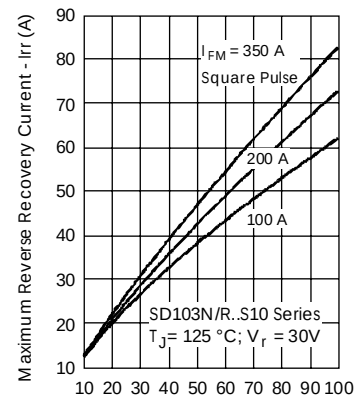
Rate Of Fall Of Forward Current - di/dt (A/μs)

Fig. 10 - Recovery Time Characteristics



Rate Of Fall Of Forward Current - di/dt (A/μs)

Fig. 11 - Recovery Charge Characteristics



Rate Of Fall Of Forward Current - di/dt (A/μs)

Fig. 12 - Recovery Current Characteristics

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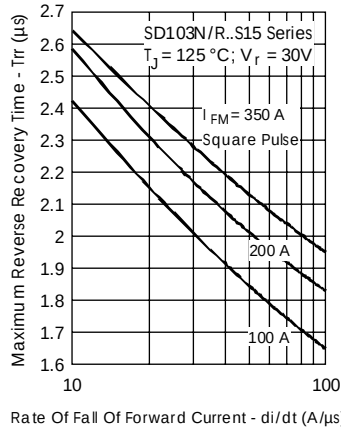


Fig. 13 - Recovery Time Characteristics

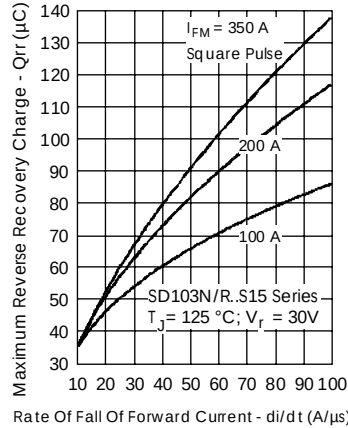


Fig. 14 - Recovery Charge Characteristics

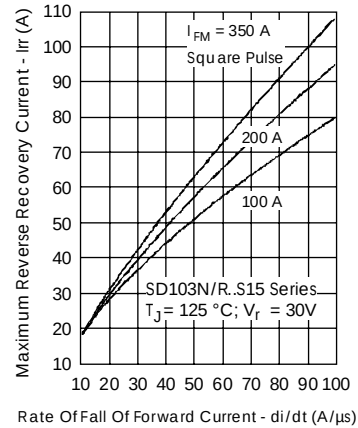


Fig. 15 - Recovery Current Characteristics

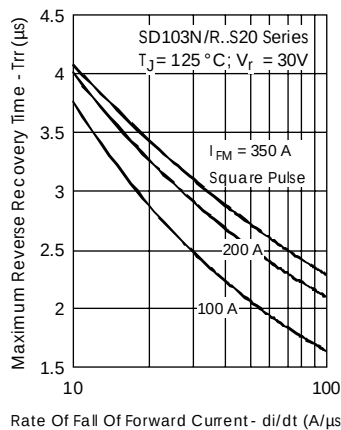


Fig. 16 - Recovery Time Characteristics

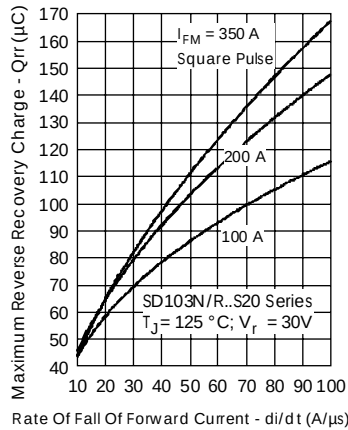


Fig. 17 - Recovery Charge Characteristics

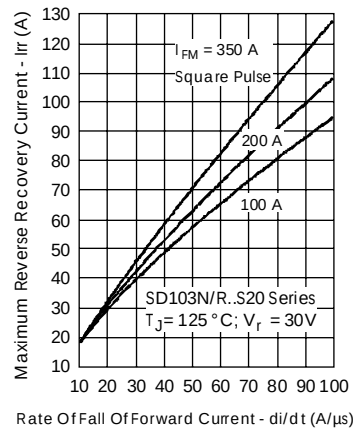


Fig. 18 - Recovery Current Characteristics

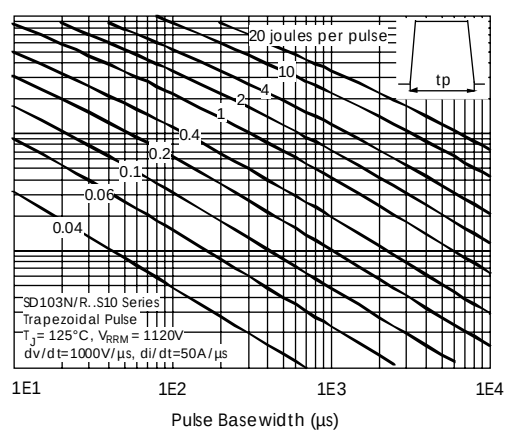
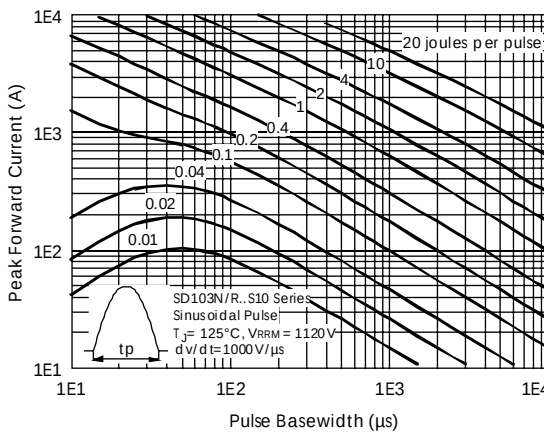


Fig. 19 - Maximum Total Energy Loss Per Pulse Characteristics

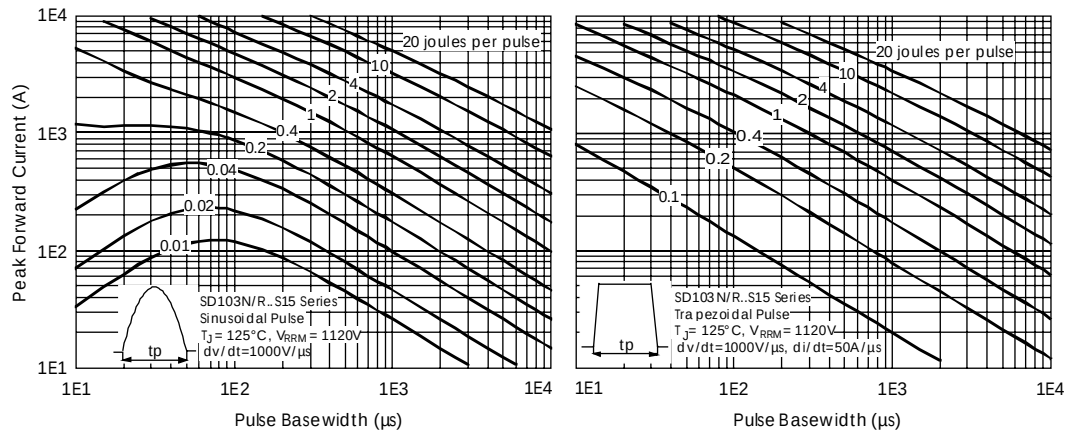


Fig. 20 - Maximum Total Energy Loss Per Pulse Characteristics

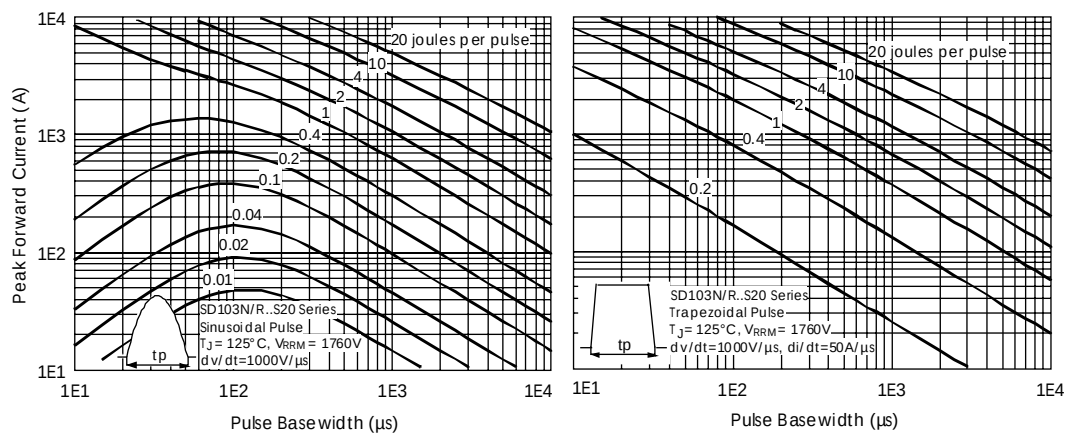


Fig. 21 - Maximum Total Energy Loss Per Pulse Characteristics